

### INCHANGE SEMICONDUCTOR

## **Isc N-Channel MOSFET Transistor**

# **TK12P60W**

### • FEATURES

- With To-252(DPAK) package
- Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

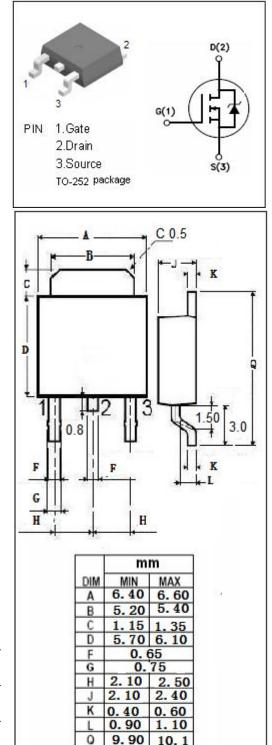
Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	600	v				
V <sub>GSS</sub>	Gate-Source Voltage	±30	∧v				
ID	Drain Current-Continuous	11.5	A				
I <sub>DM</sub>	Drain Current-Single Pulsed	46	A				
PD	Total Dissipation @T <sub>C</sub> =25°C	100	W				
T <sub>ch</sub>	Max. Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.25	°C <b>/W</b>	
Rth(ch-a)	Channel-to-ambient thermal resistance	50	°C/W	

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### isc website: www.iscsemi.cn

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### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	600			v
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.6mA	2.7		3.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =5.8A		265	340	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V			±1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V			10	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =11.5A, V <sub>GS</sub> = 0 V			1.7	V

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